TOSHIBA Transistor Silicon PNP Triple Diffused Type

# 2SA1942

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#### **Power Amplifier Applications**

- High breakdown voltage:  $V_{\rm CEO} = -160 \text{ V (min)}$
- Complementary to 2SC5199
- Recommended for 80-W high-fidelity audio frequency amplifier output stage

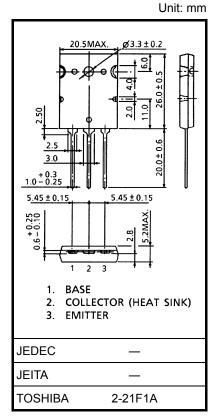
### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-160	V
Collector-emitter voltage	V <sub>CEO</sub>	-160	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	IC	-12	Α
Base current	ΙB	-1.2	Α
Collector power dissipation (Tc = 25°C)	PC	120	W
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	−55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 9.75 g (typ.)

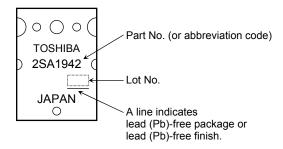


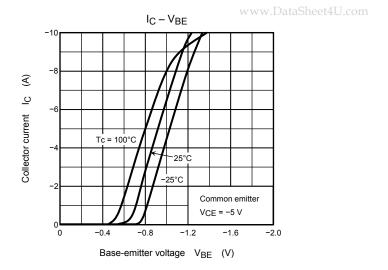
## **Electrical Characteristics (Ta = 25°C)**

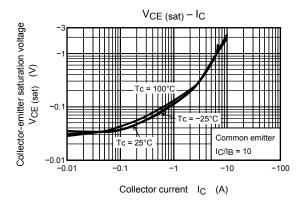
Characteristics	Symbol	Test Condition	Min	Тур.	www.Da Max	ıtaSheet Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -160 V, I <sub>E</sub> = 0	_	_	-5.0	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -5 V, I <sub>C</sub> = 0	_	_	-5.0	μΑ
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = -50 mA, I <sub>B</sub> = 0	-160	_	_	V
DC current gain  (Note here (2)	h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -1 A	55	_	160	
	h <sub>FE</sub> (2)	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -6 A	35	80	_	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = -8 A, I <sub>B</sub> = -0.8 A	_	-1.1	-2.5	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -6 A	_	-1.0	-1.5	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -1 A	_	30	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz	_	320	_	pF

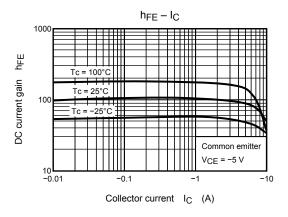
Note: hFE (1) classification R: 55 to 110, O: 80 to 160

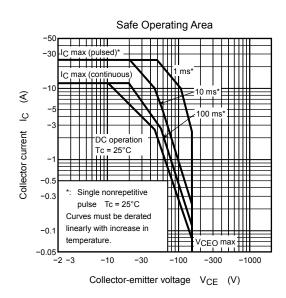
### Marking



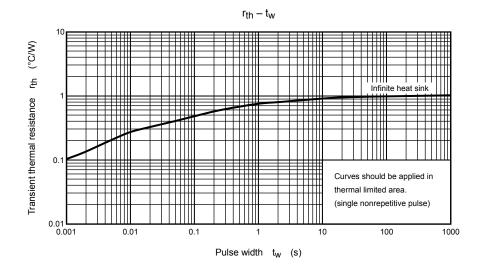








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